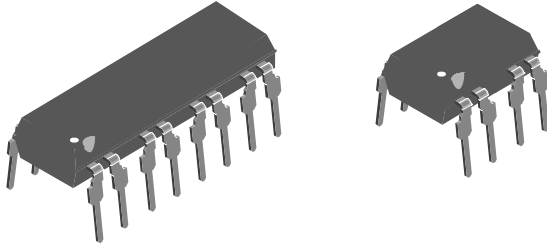
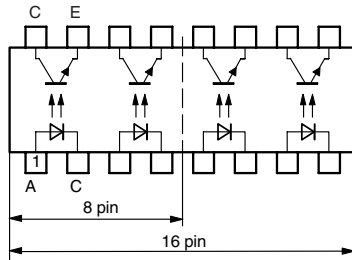


## Optocoupler, Phototransistor Output



17203-6



17203-7



### FEATURES

- DC isolation test voltage 5000 V<sub>RMS</sub>
- Compliant to RoHS directive 2002/95/EC and in accordance to WEEE 2002/96/EC



**RoHS**  
COMPLIANT

### APPLICATIONS

- Programmable logic controllers
- Modems
- Answering machines
- General applications

### AGENCY APPROVALS

- UL1577, file no. E57244 system code H, double protection
- cUL tested to CSA 22.2 bulletin 5A, UL1577, file no. E52744

### DESCRIPTION

In the K827PH, K847PH parts each channel consist of a phototransistor optically coupled to a gallium arsenide infrared-emitting diode in a 8 pin (dual); 16 pin (quad) plastic dual inline package.

### ORDER INFORMATION

PART	REMARKS
K827PH	CTR 50 % to 600 %, DIP-8
K847PH	CTR 50 % to 600 %, DIP-16

#### Note

K827PH and K847PH are marked as K827P and K847P respectively.

### ABSOLUTE MAXIMUM RATINGS <sup>(1)</sup> (T<sub>amb</sub> = 25 °C, unless otherwise specified)

PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
<b>INPUT</b>				
Reverse voltage		V <sub>R</sub>	6	V
Forward current		I <sub>F</sub>	60	mA
Forward surge current	t <sub>p</sub> ≤ 10 μs	I <sub>FSM</sub>	1.5	A
Power dissipation		P <sub>diss</sub>	100	mW
Junction temperature		T <sub>j</sub>	125	°C
<b>OUTPUT</b>				
Collector emitter voltage		V <sub>CEO</sub>	70	V
Emitter collector voltage		V <sub>ECO</sub>	7	V
Collector current		I <sub>C</sub>	50	mA
Collector peak current	t <sub>p</sub> /T = 0.5, t <sub>p</sub> ≤ 10 ms	I <sub>CM</sub>	100	mA
Power dissipation		P <sub>diss</sub>	150	mW
Junction temperature		T <sub>j</sub>	125	°C

<b>ABSOLUTE MAXIMUM RATINGS</b> <sup>(1)</sup> ( $T_{amb} = 25\text{ }^{\circ}\text{C}$ , unless otherwise specified)				
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
<b>COUPLER</b>				
AC isolation test voltage (RMS)	$t = 1\text{ min}$	$V_{ISO}$	5000	$V_{RMS}$
Total power dissipation		$P_{tot}$	250	mW
Operating ambient temperature range		$T_{amb}$	- 40 to + 100	$^{\circ}\text{C}$
Storage temperature range		$T_{stg}$	- 55 to + 125	$^{\circ}\text{C}$
Soldering temperature <sup>(2)</sup>	2 mm from case, $t \leq 10\text{ s}$	$T_{sld}$	260	$^{\circ}\text{C}$

### Notes

- <sup>(1)</sup> Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute maximum ratings for extended periods of the time can adversely affect reliability.
- <sup>(2)</sup> Refer to wave profile for soldering conditions for through hole devices.

<b>ELECTRICAL CHARACTERISTICS</b> <sup>(1)</sup> ( $T_{amb} = 25\text{ }^{\circ}\text{C}$ , unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
<b>INPUT</b>						
Forward voltage	$I_F = 50\text{ mA}$	$V_F$		1.25	1.6	V
Junction capacitance	$V_R = 0\text{ V}$ , $f = 1\text{ MHz}$	$C_j$		50		pF
<b>OUTPUT</b>						
Collector emitter voltage	$I_C = 100\text{ }\mu\text{A}$	$V_{CEO}$	70			V
Emitter collector voltage	$I_E = 100\text{ }\mu\text{A}$	$V_{ECO}$	7			V
Collector dark current	$V_{CE} = 20\text{ V}$ , $I_F = 0$ , $E = 0$	$I_{CEO}$			100	nA
<b>COUPLER</b>						
Collector emitter saturation voltage	$I_F = 10\text{ mA}$ , $I_C = 1\text{ mA}$	$V_{CEsat}$			0.3	V
Cut-off frequency	$I_F = 10\text{ mA}$ , $V_{CE} = 5\text{ V}$ , $R_L = 100\text{ }\Omega$	$f_c$		100		kHz
Coupling capacitance	$f = 1\text{ MHz}$	$C_k$		0.3		pF

### Note

- <sup>(1)</sup> Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluation. Typical values are for information only and are not part of the testing requirements.

<b>CURRENT TRANSFER RATIO</b>							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
$I_C/I_F$	$V_{CE} = 5\text{ V}$ , $I_F = 5\text{ mA}$	K827PH	CTR	50		600	%
		K847PH	CTR	50		600	%

SWITCHING CHARACTERISTICS						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Delay time	$V_S = 5\text{ V}$ , $I_C = 2\text{ mA}$ , $R_L = 100\ \Omega$ (see figure 1)	$t_d$		3		$\mu\text{s}$
Rise time	$V_S = 5\text{ V}$ , $I_C = 2\text{ mA}$ , $R_L = 100\ \Omega$ (see figure 1)	$t_r$		3		$\mu\text{s}$
Fall time	$V_S = 5\text{ V}$ , $I_C = 2\text{ mA}$ , $R_L = 100\ \Omega$ (see figure 1)	$t_f$		4.7		$\mu\text{s}$
Storage time	$V_S = 5\text{ V}$ , $I_C = 2\text{ mA}$ , $R_L = 100\ \Omega$ (see figure 1)	$t_s$		0.3		$\mu\text{s}$
Turn-on time	$V_S = 5\text{ V}$ , $I_C = 2\text{ mA}$ , $R_L = 100\ \Omega$ (see figure 1)	$t_{on}$		6		$\mu\text{s}$
Turn-off time	$V_S = 5\text{ V}$ , $I_C = 2\text{ mA}$ , $R_L = 100\ \Omega$ (see figure 1)	$t_{off}$		5		$\mu\text{s}$
Turn-on time	$V_S = 5\text{ V}$ , $I_F = 10\text{ mA}$ , $R_L = 1\text{ k}\Omega$ (see figure 2)	$t_{on}$		9		$\mu\text{s}$
Turn-off time	$V_S = 5\text{ V}$ , $I_F = 10\text{ mA}$ , $R_L = 1\text{ k}\Omega$ (see figure 2)	$t_{off}$		18		$\mu\text{s}$

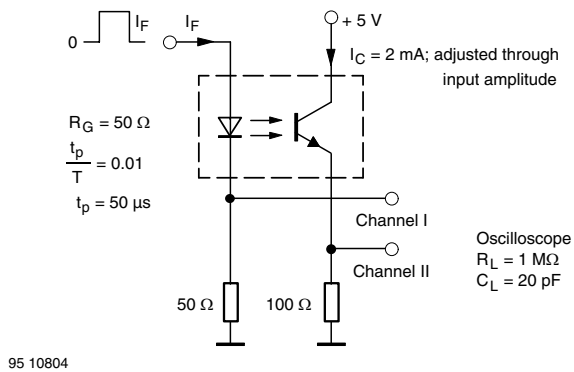


Fig. 1 - Test Circuit, Non-Saturated Operation

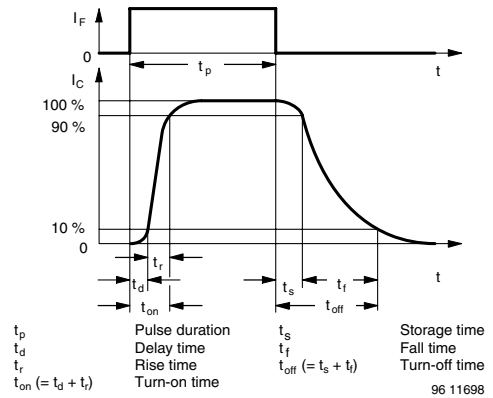


Fig. 3 - Switching Times

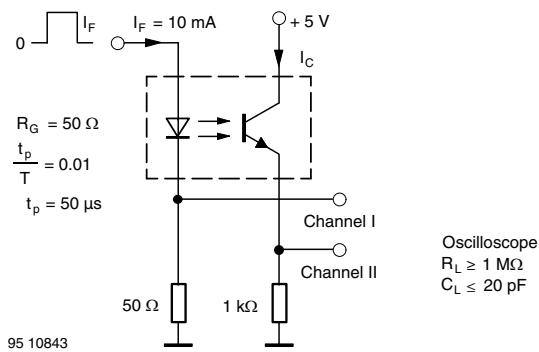


Fig. 2 - Test Circuit, Saturated Operation

**TYPICAL CHARACTERISTICS** ( $T_{amb} = 25\text{ }^{\circ}\text{C}$ , unless otherwise specified)

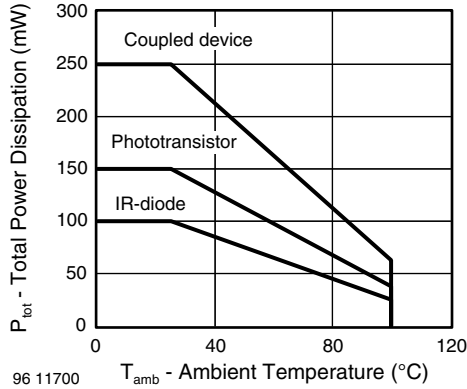


Fig. 4 - Total Power Dissipation vs. Ambient Temperature

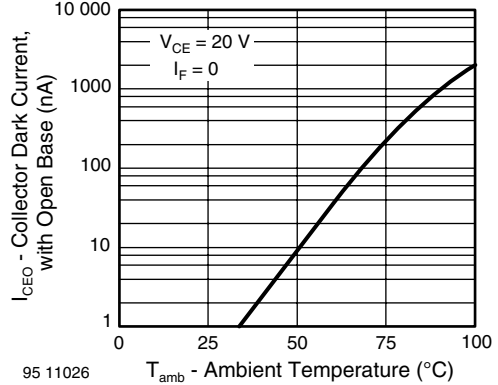


Fig. 7 - Collector Dark Current vs. Ambient Temperature

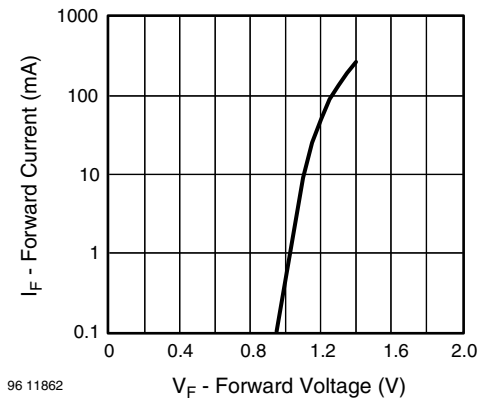


Fig. 5 - Forward Current vs. Forward Voltage

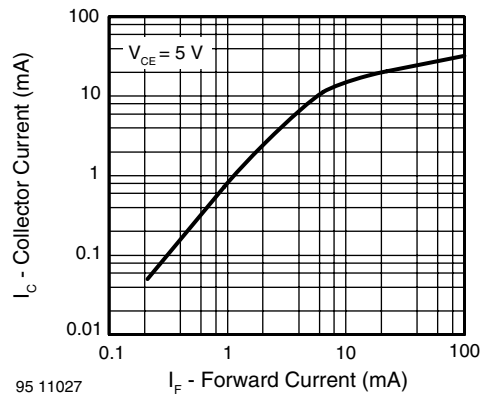


Fig. 8 - Collector Current vs. Forward Current

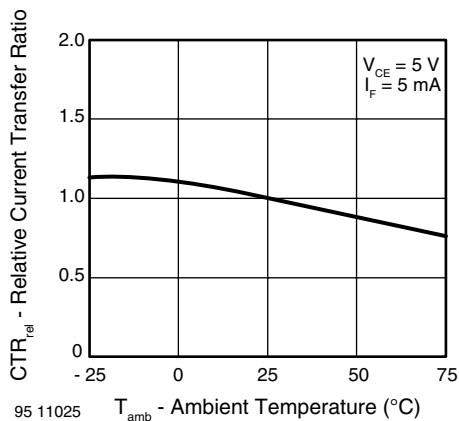


Fig. 6 - Relative Current Transfer Ratio vs. Ambient Temperature

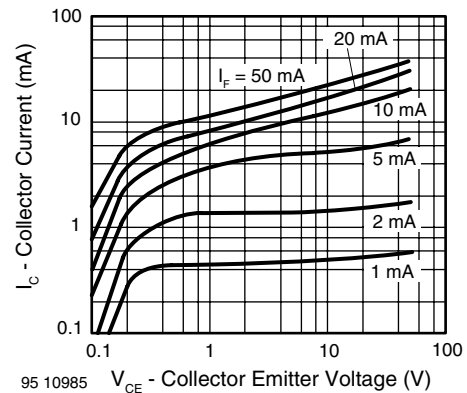


Fig. 9 - Collector Current vs. Collector Emitter Voltage

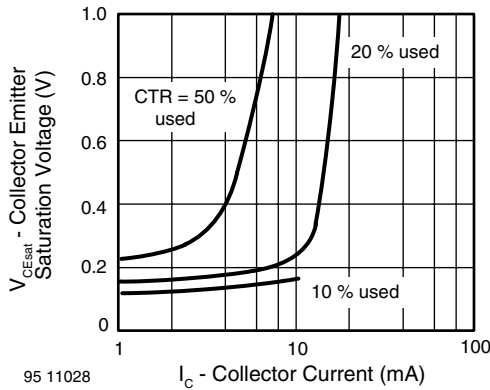


Fig. 10 - Collector Emitter Saturation Voltage vs. Collector Current

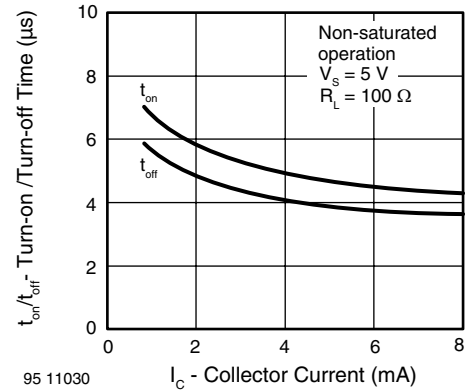


Fig. 13 - Turn-on/off Time vs. Collector Current

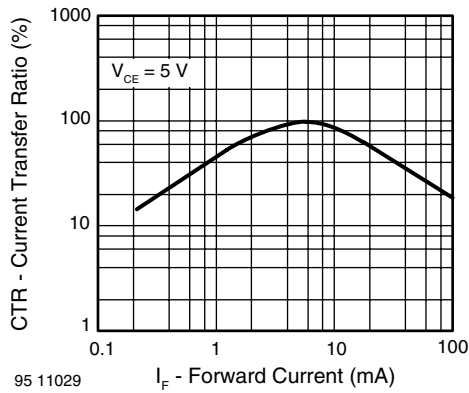


Fig. 11 - Current Transfer Ratio vs. Forward Current

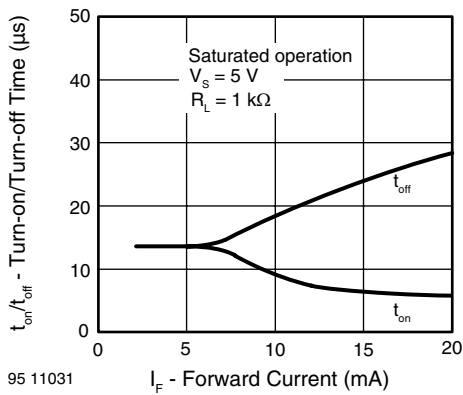


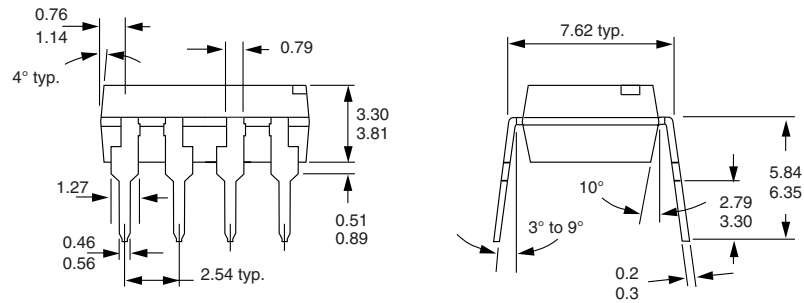
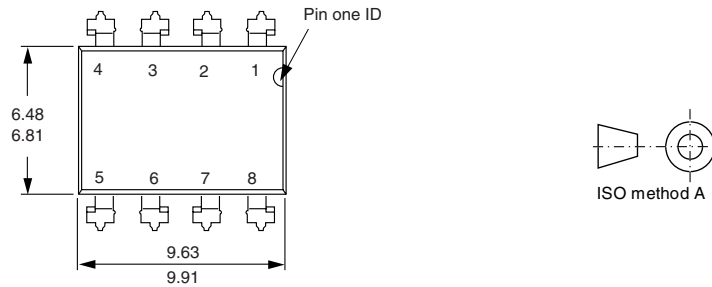
Fig. 12 - Turn-on/Turn-off Time vs. Forward Current

# K827PH, K847PH

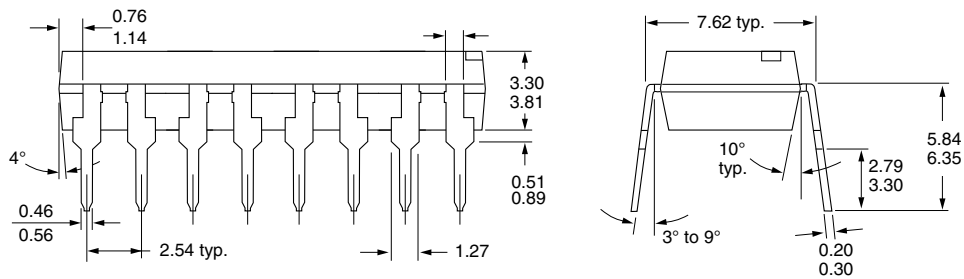
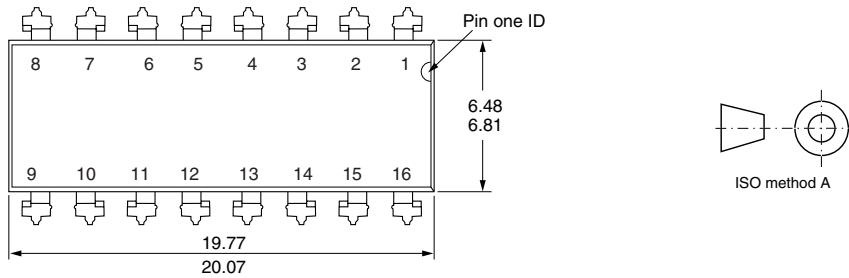
Vishay Semiconductors Optocoupler, Phototransistor Output



## PACKAGE DIMENSIONS in millimeters

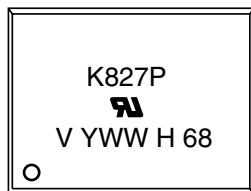


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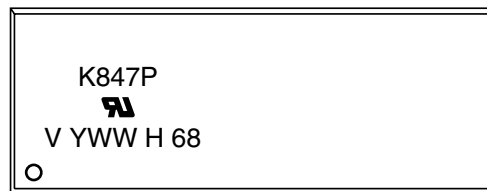


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## PACKAGE MARKING



21764-50



21764-51



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